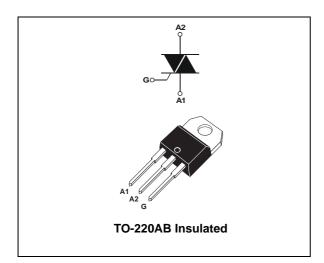


### 20 A Snubberless™ Triacs

Datasheet - production data



#### **Features**

- I<sub>T(RMS)</sub> = 20 A
- V<sub>DRM</sub>, V<sub>RRM</sub> = 600 and 700 V
- I<sub>GT (Q1)</sub> (max) = 35 and 50 mA

#### **Description**

The BTA20 Triacs use high performance glass passivated chip technology. The Snubberless concept offers suppression of the RC network and is suitable for applications such as phase control and static switching on inductive or resistive load.

Thanks to their clip assembly technique, the BTA20 Triacs provide a superior performance in surge current handling capabilities.

By using an internal ceramic pad, the BTA series provides voltage insulated tab (rated at 2500 V rms) complying with UL standards (File ref.: E81734).

TM: Snubberless is a trademark of STMicroelectronics.

Characteristics BTA20

### 1 Characteristics

Table 1. Absolute maximum ratings

Symbol	Paramete	Value	Unit			
I <sub>T(RMS)</sub>	On-state rms current (full sine wave)	20	Α			
1.	Non repetitive surge peak on-state	F = 50 Hz	t = 10 ms	210	Α	
I <sub>TSM</sub>	current (full cycle, T <sub>j</sub> initial = 25°C)	F = 60 Hz	t = 8.3 ms	200		
l <sup>2</sup> t	I <sup>2</sup> t Value for fusing	t <sub>p</sub> = 10 ms		200	A <sup>2</sup> s	
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$	Repetitive F = 50 Hz	T <sub>i</sub> = 125 °C	50	A/µs	
		Non repetitive		100		
V <sub>DSM</sub> , V <sub>RSM</sub>	Non repetitive peak off-state voltage	off-state voltage $t_p = 10 \text{ ms}$		V <sub>DRM</sub> /V <sub>RRM</sub> 100	V	
I <sub>GM</sub>	Peak gate current	t <sub>p</sub> = 20 μs	T <sub>j</sub> = 125 °C	4	Α	
$V_{GM}$	Peak positive gate voltage	16	V			
P <sub>G(AV)</sub>	Average gate power dissipation	1	W			
T <sub>stg</sub>	Storage junction temperature range	- 40 to + 150	°C			
T <sub>j</sub>	Operating junction temperature range	- 40 to + 125				

Table 2. Electrical characteristics ( $T_j = 25$  °C, unless otherwise specified)

Symbol	Test conditions	Quadrant		BTA20		Unit	
Symbol	rest conditions	Quadrant		BW	CW	Jill	
I <sub>GT</sub> <sup>(1)</sup>		A.I.I.	Min.	2	1	A	
'GT ` ′	$V_D = 12 \text{ V}, R_L = 33 \Omega$	ALL	Max.	50	35	- mA	
V <sub>GT</sub>		ALL	Max.	1.5		V	
$V_{\sf GD}$	$V_D = V_{DRM}$ , $R_L = 3.3 \text{ k}\Omega$ , $T_j = 125 \text{ °C}$	ALL	Min.	0	.2	V	
I <sub>H</sub> <sup>(2)</sup>	I <sub>T</sub> = 500 mA, gate open		Max.	75	50	mA	
	I <sub>G</sub> = 1.2 I <sub>GT</sub>	I - III	Tun	50	-	mA	
ΙL		II	Тур.	90	-		
		1 - 11 - 111	Max.	-	80		
dV/dt (2)	V <sub>D</sub> = 67% V <sub>DRM,</sub> gate open	T <sub>j</sub> = 125 °C	Тур.	750	500	1///	
av/at (=/			Min.	500	250	V/µs	
(d)//dt) a (2)	(dl/dt)c = 20 A/ms	T <sub>j</sub> = 125 °C	= 125 °C Typ. Min.	36	22	V/µs	
(αν/ατ)ε (Δ				18	11		

<sup>1.</sup> Minimum  $I_{\mbox{\scriptsize GT}}$  is guaranteed at 5% of  $I_{\mbox{\scriptsize GT}}$  max.



2/8 DocID2932 Rev 4

<sup>2.</sup> For both polarities of A2 referenced to A1.

BTA20 Characteristics

Table	3	Static characteristic	9
Iabic	J.	Static Characteristic	

Symbol		Value	Unit		
V <sub>TM</sub> <sup>(1)</sup>	$I_{TM} = 28 \text{ A}, t_p = 380  \mu\text{s}$	T <sub>j</sub> = 125 °C	Max.	1.70	V
I <sub>DRM</sub>	V -V	T <sub>j</sub> = 125 °C	Max.	10	μA
I <sub>RRM</sub>	$V_{DRM} = V_{RRM}$	T <sub>j</sub> = 125 °C	iviax.	3	mA

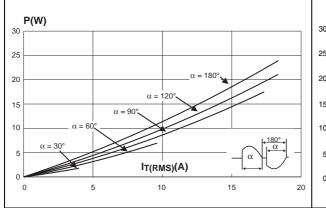
<sup>1.</sup> For both polarities of A2 referenced to A1.

**Table 4. Thermal resistances** 

Symbol	Parameter	Value	Unit
R <sub>th(j-c)</sub>	Junction to case for AC	2.1	
R <sub>th(j-c)</sub>	Junction to case for DC	2.8	°C/W
R <sub>th(j-a)</sub>	Junction to ambient	60	

Figure 1. Maximum power dissipation versus on-state rms current (full cycle)

Figure 2. Correlation between maximum rms power dissipation and maximum allowable temperatures



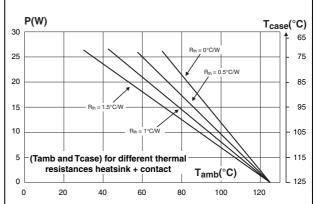
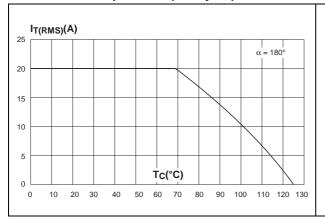
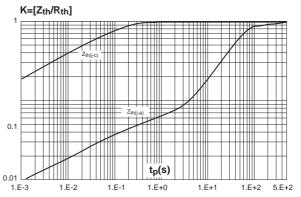


Figure 3. On-state rms current versus case temperature (full cycle)

Figure 4. Relative variation of thermal impedance versus pulse duration





Characteristics BTA20

Figure 5. On-state characteristics (maximum values)

Figure 6. Non repetitive surge peak on-state current versus number of cycles

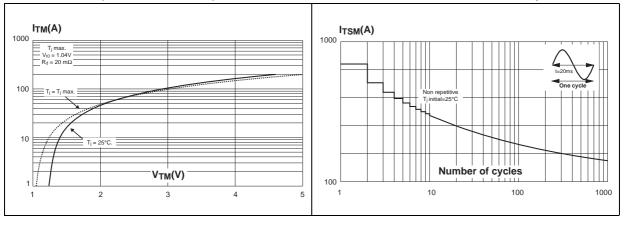
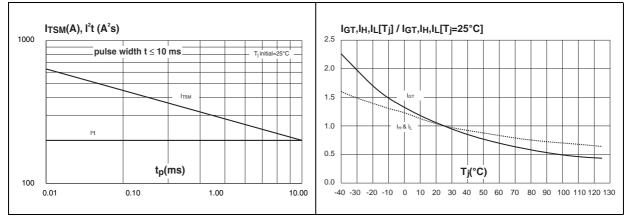


Figure 7. Non repetitive surge peak on-state current for a sinusoidal pulse and corresponding value of I<sup>2</sup>t

Figure 8. Relative variation of gate trigger current and holding current versus junction temperature



577

4/8 DocID2932 Rev 4

BTA20 Package information

## 2 Package information

- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

С В b2 Ø١ F Gate note1 14 13 c2 a1 12 a2 с1 b1

Figure 9. TO-220AB package dimensions (definitions)

577

DocID2932 Rev 4 5/8

Package information BTA20

Table 5. TO-220AB package dimension values

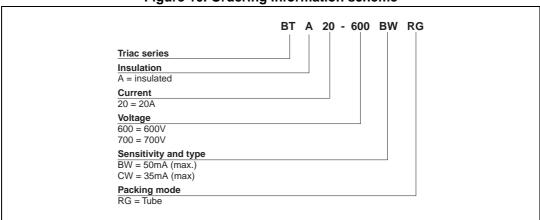
	Dimensions							
Ref.	Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α	15.20		15.90	0.598		0.625		
a1		3.75			0.147			
a2	13.00		14.00	0.511		0.551		
В	10.00		10.40	0.393		0.409		
b1	0.61		0.88	0.024		0.034		
b2	1.23		1.32	0.048		0.051		
С	4.40		4.60	0.173		0.181		
c1	0.49		0.70	0.019		0.027		
c2	2.40		2.72	0.094		0.107		
е	2.40		2.70	0.094		0.106		
F	6.20		6.60	0.244		0.259		
I	3.75		3.85	0.147		0.151		
14	15.80	16.40	16.80	0.622	0.646	0.661		
L	2.65		2.95	0.104		0.116		
12	1.14		1.70	0.044		0.066		
13	1.14		1.70	0.044		0.066		
М		2.60			0.102			



BTA20 Ordering information

# 3 Ordering information

Figure 10. Ordering information scheme



**Table 6. Product selector** 

Order code	Voltage		Sensitivity	Type	Bookogo	
Order code	600 V	700 V	Sensitivity	туре	Package	
BTA20-600CWRG	Χ		35 mA			
BTA20-700BWRG		Х	50 mA	Snubberless	TO-220AB Ins.	
BTA20-700CWRG		Х	35 mA			

**Table 7. Ordering information** 

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BTA20-600CWRG	BTA20-600CW				
BTA20-700BWRG	BTA20-700BW	TO-220AB Ins.	2.3 g	50	Tube
BTA20-700CWRG	BTA20-700CW				

## 4 Revision history

**Table 8. Document revision history** 

Date Revision		Changes			
Sep-2001	1A	Initial release.			
08-Feb-2006	2	TO-220AB Ins. delivery mode changed from bulk to tube.			
09-Jul-2012	3	Updated dl/dt repetitive value in Table 1.			
01-Sep-2014	4	Updated V <sub>DRM</sub> /V <sub>RRM</sub> value in <i>Table 1</i> .			



7/8

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57

8/8 DocID2932 Rev 4